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IN THE UNITED STATES PATENT AND TRADE MARKS OFFICE

Applicant:

Richard C. Foss

Serial No:

08/147,038

Filed:

November 4, 1993

Title:

DYNAMIC RANDOM ACCESS MEMORY USING

IMPERFECT ISOLATING TRANSISTORS

FAX COPY RECEIVED

Art Unit:

25**P**&

OCT 1 3 1994

Examiner:

Tan Dinh

GROUP 2500

Our File:

243P11US-C2

October 13, 1994

The Commissioner of Patents and Trade Marks, Washington, D.C., 20231 U.S.A.

Dear Sir:

This is in response to the official action dated July 27th, 1994 in the above-identified application.

Please amend the claims as follows:

- 6. (Twice amended) A dynamic random access memory (DRAM) as defined in claim 1, further comprising:
 - [(a) a plurality of bit storage capacitors,
- (b) a folded bit line for receiving charge storedon one of said capacitors having bit line capacitance,
- (c) a sense amplifier having a pair of sense nodes for sensing a voltage differential across said sense nodes,]

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